# imall

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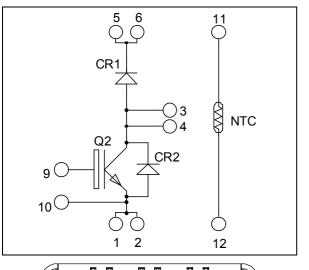
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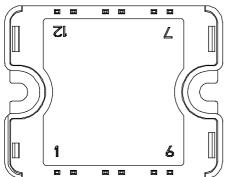




### **Boost chopper NPT IGBT Power Module**

# $V_{CES} = 1200V$ $I_{C} = 75A$ @ Tc = 80°C





Pins 1/2; 3/4; 5/6 must be shorted together

#### Application

- AC and DC motor control
- Switched Mode Power Supplies
- Power Factor Correction

#### Features

- Non Punch Through (NPT) Fast IGBT
  - Low voltage drop
  - Low tail current
  - Switching frequency up to 50 kHz
  - Soft recovery parallel diodes
  - Low diode VF
  - Low leakage current
  - RBSOA and SCSOA rated
- Very low stray inductance
- Internal thermistor for temperature monitoring
- High level of integration

#### Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package) •
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- **RoHS** Compliant

#### Absolute maximum ratings

_	Symbol	Parameter		Max ratings	Unit
	V <sub>CES</sub>	Collector - Emitter Breakdown Voltage		1200	V
	I <sub>C</sub>	Continuous Collector Current	$T_c = 25^{\circ}C$	100	
	IC	Continuous Conector Current	$T_c = 80^{\circ}C$	75	А
	I <sub>CM</sub>	Pulsed Collector Current	$T_c = 25^{\circ}C$	150	
	V <sub>GE</sub>	Gate – Emitter Voltage		±20	V
	P <sub>D</sub>	Maximum Power Dissipation	$T_c = 25^{\circ}C$	500	W
	RBSOA	Reverse Bias Safe Operating Area	$T_j = 150^{\circ}C$	150A @ 1200V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

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#### All ratings (a) $T_j = 25^{\circ}C$ unless otherwise specified

#### **Electrical Characteristics**

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
Т	Zero Gate Voltage Collector Current	$V_{GE} = 0V$	$T_j = 25^{\circ}C$			250	۸
I <sub>CES</sub>		$V_{CE} = 1200V$ $T_j = 2$	$T_j = 125^{\circ}C$			500	μA
V	Collector Emitter saturation Voltage	$V_{GE} = 15V$	$T_j = 25^{\circ}C$		3.2	3.7	V
V <sub>CE(sat)</sub>		$I_C = 75A$	$T_{j} = 125^{\circ}C$		3.9		v
V <sub>GE(th)</sub>	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 2.5 \text{ mA}$		4.5		6.5	V
I <sub>GES</sub>	Gate – Emitter Leakage Current	$V_{GE} = \pm 20V, V_{CE} = 0V$				±500	nA

#### **Dynamic Characteristics**

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$			5.1		
Coes	Output Capacitance	$V_{CE} = 25V$	$V_{CE} = 25V$		0.7		nF
C <sub>res</sub>	Reverse Transfer Capacitance	f = 1 MHz			0.4		
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive Switching (25°C) $V_{GE} = 15V$ $V_{Bus} = 600V$ $I_C = 75A$ $R_G = 7.5\Omega$			120		
Tr	Rise Time				50		
T <sub>d(off)</sub>	Turn-off Delay Time				310		ns
$T_{\rm f}$	Fall Time				20		
T <sub>d(on)</sub>	Turn-on Delay Time	Inductive Switch	ing (125°C)		130		
Tr	Rise Time	$V_{GE} = 15V$ $V_{Bus} = 600V$ $I_C = 75A$			60		
T <sub>d(off)</sub>	Turn-off Delay Time				360		ns
$T_{\rm f}$	Fall Time	$R_G = 7.5\Omega$			30		
Eon	Turn-on Switching Energy	$V_{GE} = 15V$ $V_{Bus} = 600V$	$T_j = 125^{\circ}C$		9		mI
E <sub>off</sub>	Turn-off Switching Energy	$I_{C} = 75A$ $R_{G} = 7.5\Omega$	$T_j = 125^{\circ}C$		4		mJ

#### Chopper diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V <sub>RRM</sub>	Maximum Peak Repetitive Reverse Voltage			1200			V
I <sub>RM</sub>	Maximum Reverse Leakage Current	V <sub>R</sub> =1200V	$T_j = 25^{\circ}C$ $T_j = 125^{\circ}C$			100 500	μΑ
I <sub>F</sub>	DC Forward Current		$Tc = 70^{\circ}C$		60		А
	Diode Forward Voltage	$I_F = 60A$			2.5	3	
$V_{\rm F}$		$I_F = 120A$			3		V
		$I_F = 60A$	$T_j = 125^{\circ}C$		1.8		
t	Reverse Recovery Time	I = 60A	$T_j = 25^{\circ}C$		265		ns
t <sub>rr</sub>			$T_{j} = 125^{\circ}C$		350		115
Q <sub>rr</sub>	Reverse Recovery Charge	di/dt =200A/ $\mu$ s T <sub>j</sub> = 2	$T_j = 25^{\circ}C$		560		nC
٦rr			$T_{j} = 125^{\circ}C$		2890		ne



#### Thermal and package characteristics

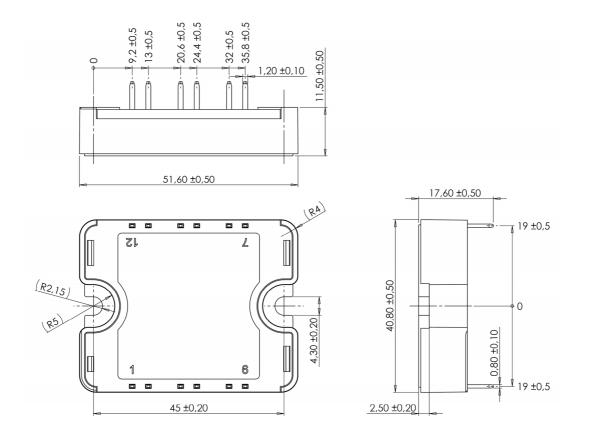
Symbol	Characteristic		Min	Тур	Max	Unit	
R <sub>thJC</sub>	Junction to Case Thermal Resistance		IGBT		0.25	0.25	°C/W
<b>R</b> <sub>th</sub> JC			Diode			0.9	C/ W
V <sub>ISOL</sub>	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T <sub>J</sub>	Operating junction temperature range		-40		150		
T <sub>STG</sub>	Storage Temperature Range		-40		125	°C	
T <sub>C</sub>	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsin	k M4	2		3	N.m
Wt	Package Weight				80	g	

Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic	Min	Тур	Max	Unit
R <sub>25</sub>	Resistance @ 25°C		50		kΩ
B 25/85	$T_{25} = 298.15 \text{ K}$		3952		Κ

$$R_{T} = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$$
 T: Thermistor temperature  
R<sub>T</sub>: Thermistor value at T

#### SP1 Package outline (dimensions in mm)



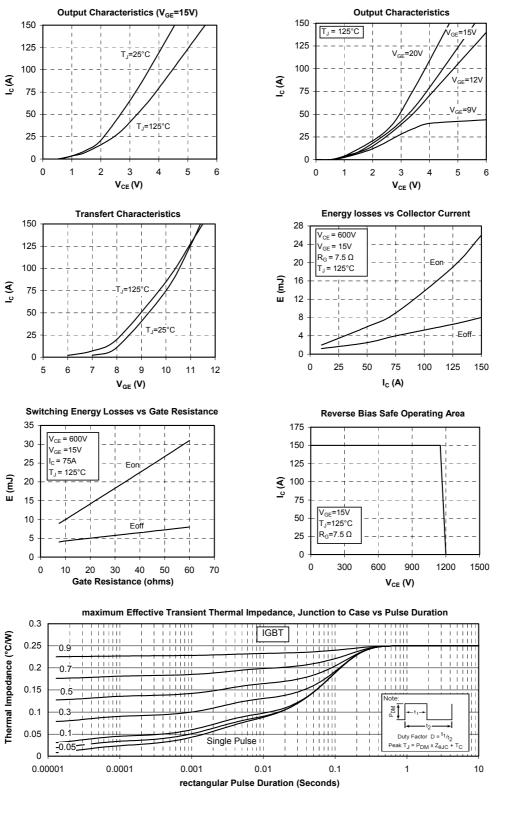
See application note 1904 - Mounting Instructions for SP1 Power Modules on www.microsemi.com

www.microsemi.com

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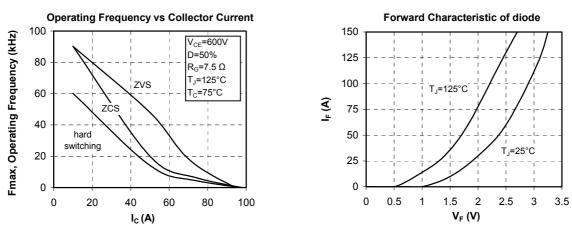


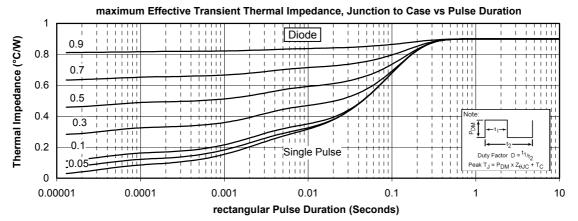
#### **Typical Performance Curve**



## APTGF75DA120T1G









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